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# ***Novel In-Plane Semiconductor Lasers XIV***

**Alexey A. Belyanin**  
**Peter M. Snowton**  
*Editors*

**9–12 February 2015**  
**San Francisco, California, United States**

*Sponsored and Published by*  
SPIE

**Volume 9382**

Proceedings of SPIE 0277-786X, V. 9382

SPIE is an international society advancing an interdisciplinary approach to the science and application of light.

Novel In-Plane Semiconductor Lasers XIV, edited by Alexey A. Belyanin, Peter M. Snowton, Proc. of SPIE  
Vol. 9382, 938201 · © 2015 SPIE · CCC code: 0277-786X/15/\$18 · doi: 10.1117/12.2192733

Proc. of SPIE Vol. 9382 938201-1

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Author(s), "Title of Paper," in *Novel In-Plane Semiconductor Lasers XIV*, edited by Alexey A. Belyanin, Peter M. Smowton, Proceedings of SPIE Vol. 9382 (SPIE, Bellingham, WA, 2015) Article CID Number.

ISSN: 0277-786X

ISBN: 9781628414721

Published by

**SPIE**

P.O. Box 10, Bellingham, Washington 98227-0010 USA

Telephone +1 360 676 3290 (Pacific Time) · Fax +1 360 647 1445

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